

## Normal Capacitance ESD Protection Diode

### 1 Features

- IEC 61000-4-2 Level 4 ESD Protection
  - $\pm 30$ -kV Contact Discharge
  - $\pm 30$ -kV Air Gap Discharge
- Peak Reverse Working Voltage: 5.0 V (Maximum)
- IO Capacitance:
  - 30 pF (Typical)
- DC Breakdown Voltage: 5.8 to 8.0 V (Minimum to Maximum)
- Low Leakage Current: 0.2 $\mu$ A (Maximum)
- Industrial Temperature Range:  $-55^{\circ}\text{C}$  to  $+150^{\circ}\text{C}$
- Package DFN1006-2L

### 2 Applications

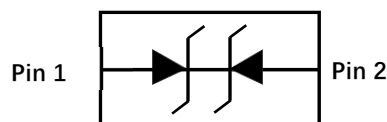
- End Equipment
  - TWS and Smart Wearable
  - TV and Monitors
  - Cellular handsets and accessories
  - Portable electronics
  - Communication systems
  - Computers and peripherals

### 3 Description

The SLEN25NCBM is a bidirectional ESD protection diode for circuit protection. The SLEN25NCBM is rated to dissipate ESD strikes at the maximum level specified in the IEC 61000-4-2 international standard (Level 4).

The low dynamic resistance and low clamping voltage ensure system level protection against transient events.

### 4 Pin Configuration



DFN1006-2L

### 5 Device Information

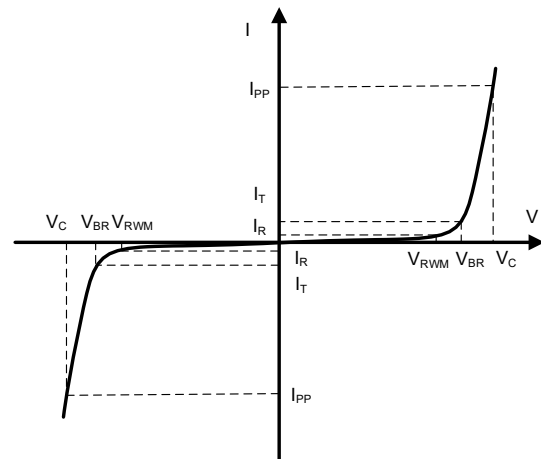
PART NUMBER	PACKAGE	BODY SIZE (NOM)
SLEN25NCBM	DFN1006-2L	1.00 mm x 0.60mm

### 6 Absolute maximum Ratings @25°C

RATING	SYMBOL	VALUE	UNITS
Peak Pulse Power ( $t_p=8/20\mu\text{s}$ )	$P_{PP}$	256	W
Peak Pulse Current ( $t_p=8/20\mu\text{s}$ )	$I_{PP}$	16	A
Operating Temperature	$T_J$	-55 to 125	$^{\circ}\text{C}$
Storage Temperature	$T_{STG}$	-55 to 150	$^{\circ}\text{C}$
ESD Protection-Contact Discharge	$V_{ESD}$	$\pm 30$	kV
ESD Protection-Air Discharge	$V_{ESD}$	$\pm 30$	kV

**7 Electronics Parameter Definitions**

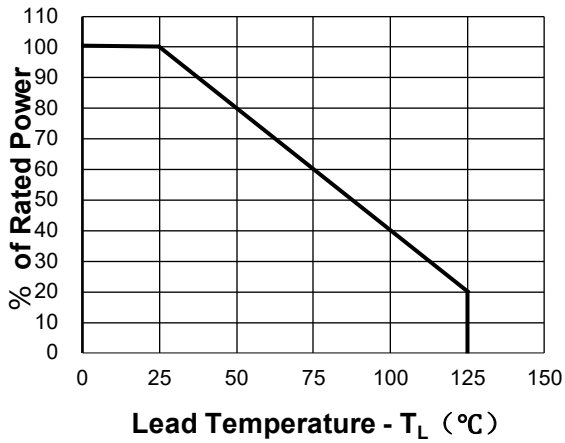
Symbol	Parameter
$V_{RWM}$	Peak Reverse Working Voltage
$I_R$	Reverse Leakage Current @ $V_{RWM}$
$V_{BR}$	Breakdown Voltage @ $I_T$
$I_T$	Test Current
$I_{PP}$	Maximum Reverse Peak Pulse Current
$V_C$	Clamping Voltage @ $I_{PP}$
$P_{PP}$	Peak Pulse Power
$C_J$	Junction Capacitance



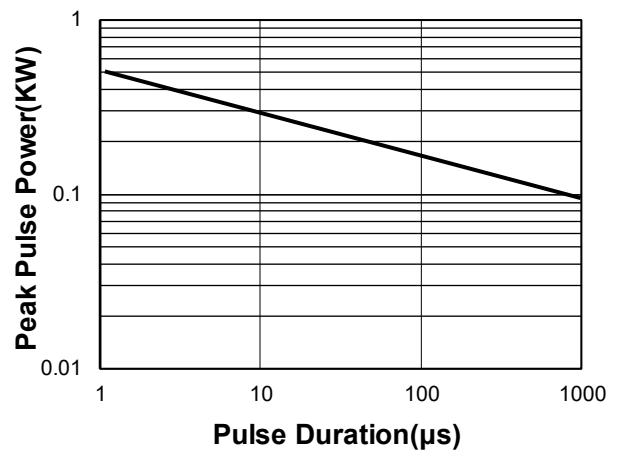
**8 Electrical characteristics (@25°C unless otherwise specified)**

PARAMETER	SYMBOL	CONDITIONS	MIN.	TYP.	MAX.	UNITS
Peak Reverse Working Voltage	$V_{RWM}$				5	V
Breakdown Voltage	$V_{BR}$	$I_T = 1\text{mA}$	5.8		8	V
Reverse Leakage Current	$I_R$	$V_{RWM} = 5\text{V}, T_A = 25^\circ\text{C}$			0.2	$\mu\text{A}$
Clamping Voltage	$V_C$	$I_{PP} = 1\text{A}, t_P = 8/20\mu\text{s}$		7	8	V
Clamping Voltage	$V_C$	$I_{PP} = 16\text{A}, t_P = 8/20\mu\text{s}$		14	16	V
Junction Capacitance	$C_j$	$V_R = 0\text{V}, f = 1\text{MHz}$		30	35	pF

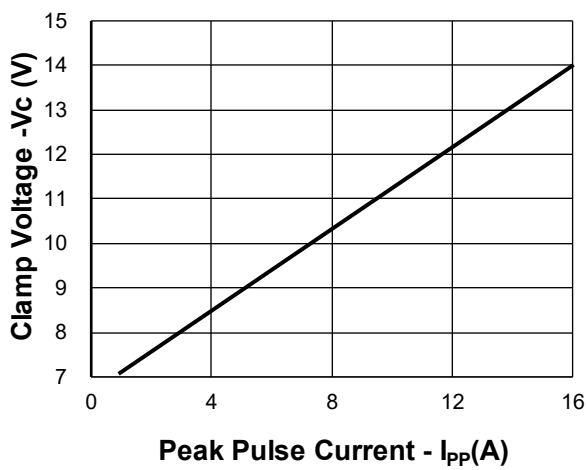
**9 Typical Characteristics**



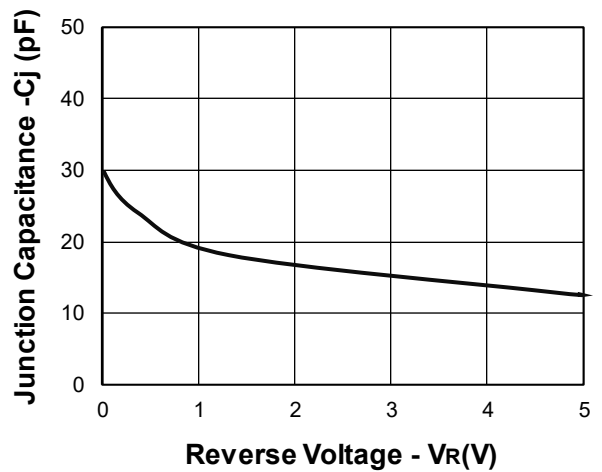
**Fig 1. Power Derating Curve**



**Fig 2. Peak Pulse Power vs. Pulse Time**

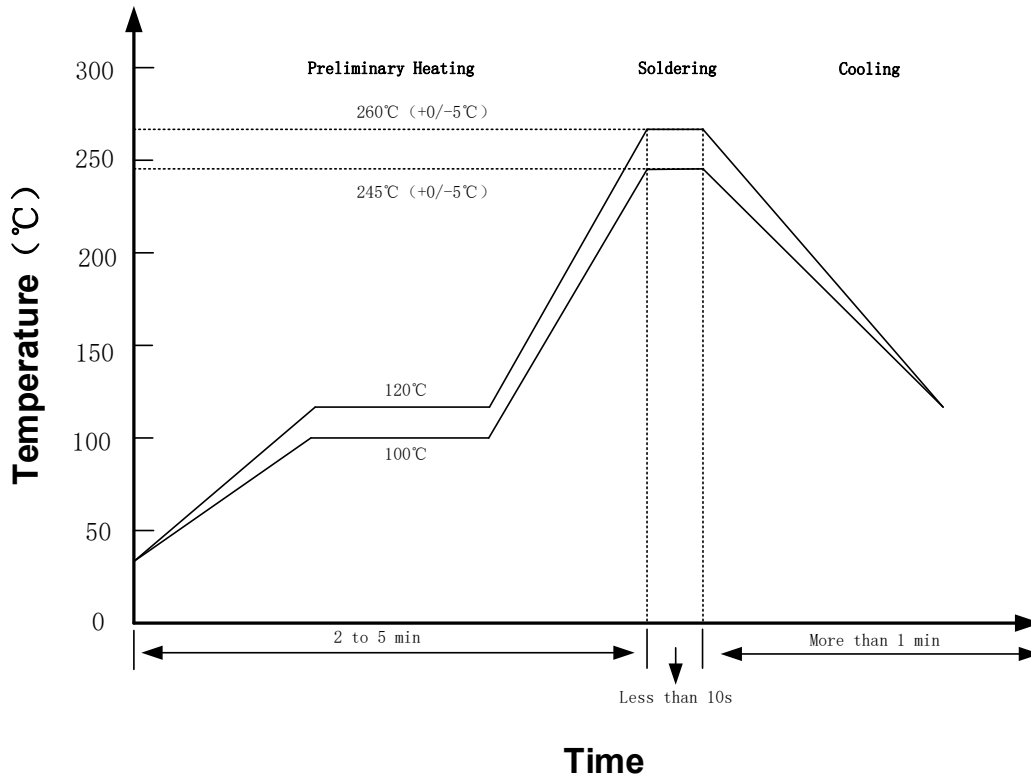


**Fig 3. Clamping Voltage vs. Peak Pulse Current**

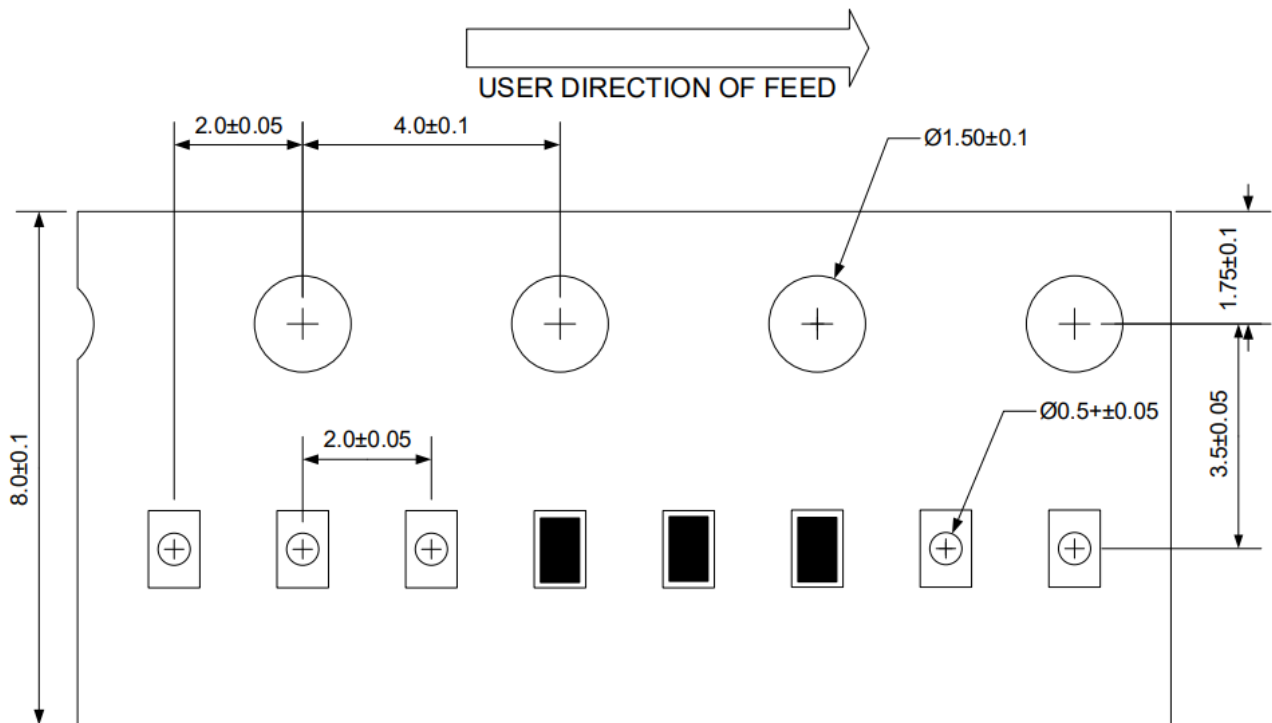


**Fig 4. Junction Capacitance vs. Reverse Voltage**

**10 Soldering Parameters**



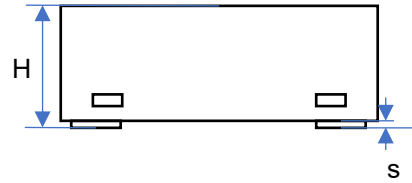
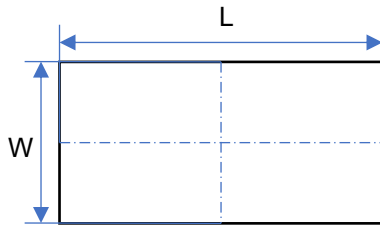
**11 Load with information**



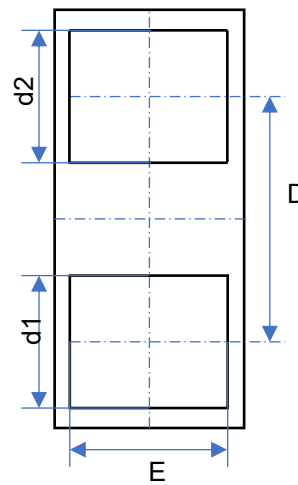
Unit:mm

**12 Product dimension**

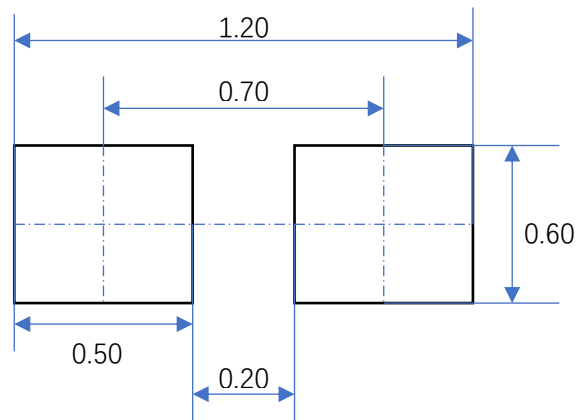
DFN1006-2L



DIM	UNITS (mm)		
	MIN.	TYP.	MAX.
L	0.95	1.00	1.08
W	0.55	0.60	0.68
H	0.39	0.50	0.55
s	0.00	0.02	0.05
D	0.60	0.65	0.70
E	0.40	0.50	0.60
d1	0.20	0.25	0.30
d2	0.20	0.25	0.30



**13 PCB Layout Footprints**



**14 Ordering Information**

Part Number	Packaging	Reel Size
SLEN25NCBM	10000/Tape & Reel	7 inch